# 2SC4672

GENERAL PURPOSE TRANSISTOR
1W 1.5A 25V NPN SILICON

## DESCRIPTION

The 2SC4672 is available in SOT-89 package

## FEATURES

- Available in SOT-89 package

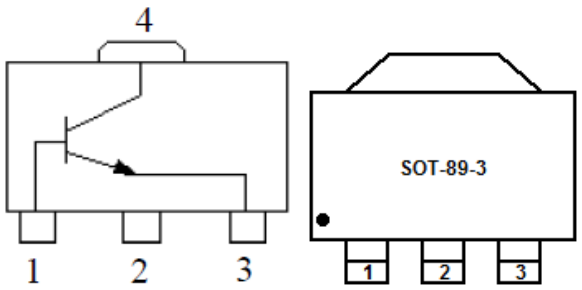
## ORDERING INFORMATION

| Package Type | Part Number |
|---|---|
| SOT-89 | 2SC4672Q |
| | 2SC4672R |
| Note | SPQ: 1,000pcs/Reel |
| AiT provides all RoHS Compliant Products | |

## APPLICATIONS

- Can be used for switching and amplifying in various electrical and electronic circuit.

## PIN DESCRIPTION



## ABSOLUTE MAXIMUM RATINGS

| | |
|---|---|
| $V_{CEO}$, Collector-Emitter Voltage($I_B$=0) | 25V |
| $V_{CBO}$, Collector-Base Voltage($I_E$=0) | 40V |
| $V_{EBO}$, Emitter-Base Voltage($I_C$=0) | 6V |
| $I_C$, Collector Current | 1.5A |
| $P_{TOT}$, Total Device Dissipation($T_A$ =25°C)[NOTE1] | 1W |
| $T_{JM}$, Junction Temperature(Max) | 150°C |
| $T_{STG}$, Storage Temperature | -55°C ~150°C |

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Device is mounted on a printed circuit board.

## ELECTRICAL CHARACTERISTICS

$T_A$=25°C, unless otherwise specified

| Parameter | Symbol | Conditions | | Min. | Typ. | Max. | Unit |
|---|---|---|---|---|---|---|---|
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | $I_C$= 2mA, $I_B$=0 | | 25 | - | - | V |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | $I_C$=100μA, $I_E$=0 | | 40 | - | - | V |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | $I_E$=100μA,$I_C$=0 | | 6 | - | - | V |
| Forward Current Transfer Ratio | $h_{FE}$ | $V_{CE}$=1V, $I_C$=100mA | Q | 120 | - | 270 | |
| | | | R | 180 | - | 390 | |
| Collector-Base Current | $I_{CBO}$ | $V_{CB}$=35V, $I_E$=0 | | - | - | 100 | nA |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C$=800mA, $I_B$=80mA | | - | - | 0.5 | V |
| Characteristic Frequency | $f_T$ | $I_C$=50mA, $V_{CE}$=10V, f=100MHz | | - | 100 | - | MHz |

## ELECTRICAL CHARACTERISTICS CURVES

Figure 1.

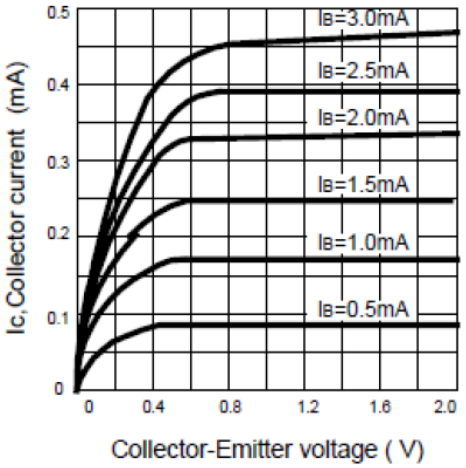



Figure 2.

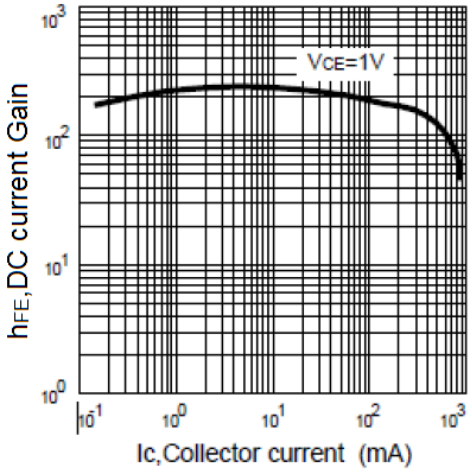



Figure 3.

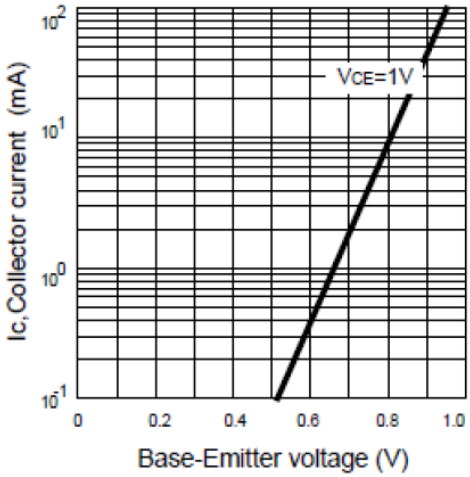



Figure 4.

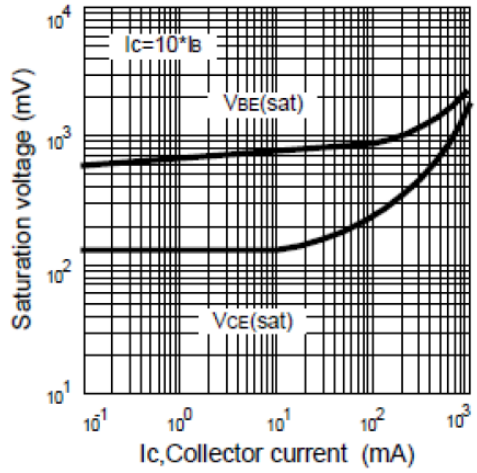



Figure 5.

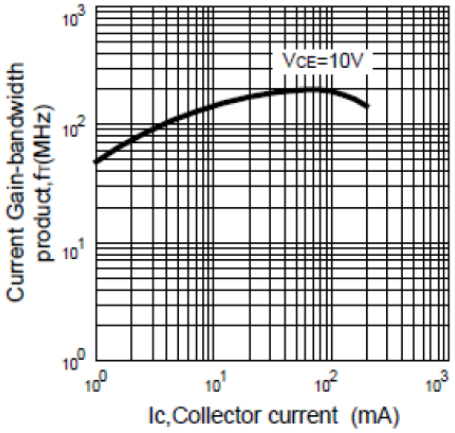
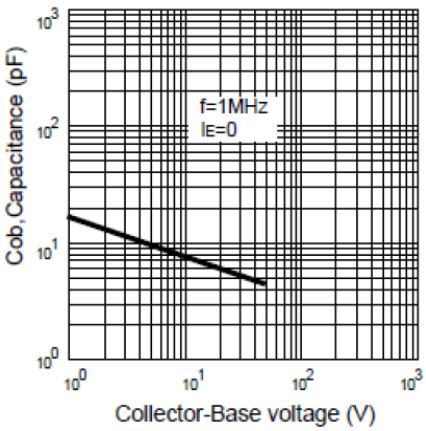
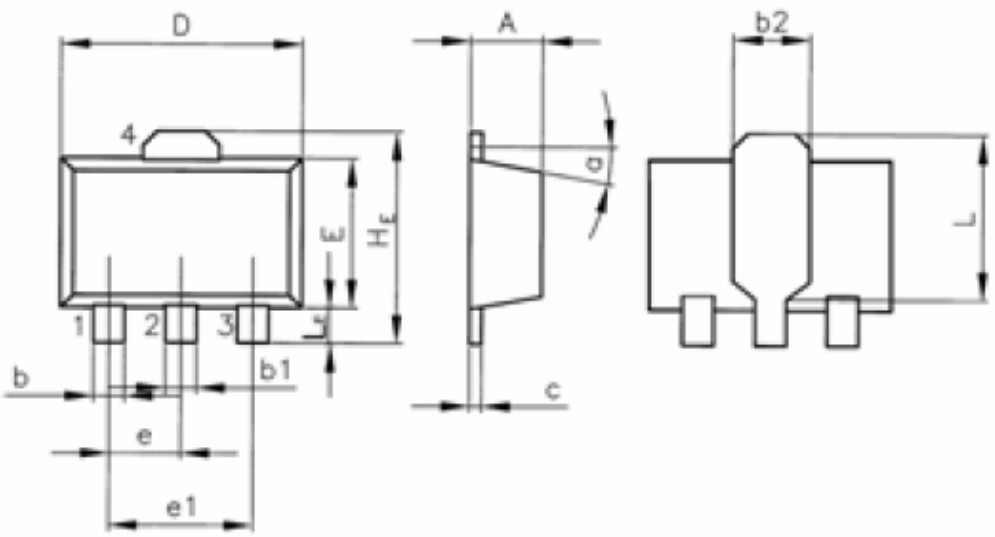



Figure 6.



## PACKAGE INFORMATION

Dimension in SOT-89 (Unit: mm)




| Symbol | Min | Typ | Max |
|---|---|---|---|
| A | 1.4 | - | 1.6 |
| b | 0.35 | - | 0.55 |
| b1 | 0.4 | - | 0.65 |
| b2 | - | 1.6 | - |
| c | 0.35 | - | 0.45 |
| D | 4.4 | - | 4.6 |
| E | 2.35 | - | 2.55 |
| e | - | 1.5 | - |
| e1 | - | 3 | - |
| $H_E$ | - | 4.15 | - |
| L | - | 2.7 | - |
| $L_E$ | - | 1.0 | - |
| α | - | 5° | - |

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